

MTM 2... 8GHz

Wideband GaN Amplifiers Module



STANDARD MODELS

Model	Frequency Range GHZ	Output Power	Input Power	Small Signal Gain	Gain Flatness	Gain Adj	Input VSWR
		min W	max dBm	min dB	max dB	max dB	typ / max
MTM0208-10	2...8	10	0	44	±2.5	NA	1.5/2
MTM0208-40	2...8	40	0	49	±2.5	NA	1.5/2
MTM0208-50	2...8	50	0	50	±2.5	NA	1.5/2

Model	Output VSWR typ / max	2nd Harmonic Power @ Pout typ / max dBc	3rd Harmonic Power@ Pout max dBc	Spur @ Pout typ / max dBc	IM3 typ / max dBc	Noise Floor typ / max dBm/MHz	Stability yes / no
MTM0208-10	2.5/3	-15/-10	-10	-65/-60	NA	-45/-40	Y
MTM0208-40	2.5/3	-15/-10	-10	-65/-60	NA	-45/-40	Y
MTM0208-50	2.5/3	-15/-10	-10	-65/-60	NA	-45/-40	Y

Model	VSWR Load	Line Power VA	Dimensions (H, D)	Weight typ kg
MTM0208-10	3	300	TBD	TBD
MTM0208-40	3	600	TBD	TBD
MTM0208-50	3	800	TBD	TBD

STANDARD SPECIFICATIONS

Overdrive Protection: up to +10 dBm for no damage
 Input Impedance: 50 Ohm nominal
 Output Impedance: 50 Ohm nominal
 Noise Figure: 10 dB max.
 Class of Operation: AB-linear

GENERAL

RF Input: SMA-f; standard on front panel
 RF Output: SMA-f; standard on front panel
 Mains Supply: <600 VA 28 V AC
 Ambient Temperature: 0 ... +45 °C
 Storage Temperature: -20 ... +65 °C



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Relative Humidity: up to 95% (non-condensing)
Operating Altitude: up to 2000 m above sea level
Vibration and Shock: normal laboratory environment
Cooling: forced air with integral blower
air intake and exhaust at rear

ACTUAL TESTING DATA

2-8GHz 100W test data

